

**Features**

- Low profile package
- Ideal for automated placement
- Ultrafast reverse recovery time
- Low power losses, high efficiency
- Low forward voltage drop
- High surge capability
- High temperature soldering:
260°C/10 seconds at terminals
- Component in accordance to
RoHS 2002/95/1 and WEEE 2002/96/EC



SMC (DO-214AB)

Mechanical Date

- **Case:** JEDEC DO-214AB molded plastic body over glass passivated chip
- **Terminals:** Solder plated, solderable per J-STD-002B and JESD22-B102D
- **Polarity:** Laser band denotes cathode end

Major Ratings and Characteristics

$I_{F(AV)}$	8.0A
V_{RRM}	20 V to 100 V
I_{FSM}	200A
V_F	0.50V, 0.55, 0.70V, 0.85V
$T_j \text{ max.}$	125 °C

Maximum Ratings & Thermal Characteristics(T_A = 25 °C unless otherwise noted)

Items	Symbol	SK82	SK83	SK84	SK85	SK86	SK88	SK810	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	20	30	40	50	60	80	100	V
Maximum RMS voltage	V_{RMS}	14	21	28	35	42	56	70	V
Maximum DC blocking voltage	V_{DC}	20	30	40	50	60	80	100	V
Maximum average forward rectified current	$I_{F(AV)}$	8.0							A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I_{FSM}	200							A
Voltage rate of change (rated V_R)	dv/dt	10000							V/μs
Thermal resistance from junction to lead ⁽¹⁾	$R_{θJL}$	20							°C/W
Operating junction and storage temperature range	T_J, T_{STG}	-65 to +125							°C

Note 1: Mounted on P.C.B. with 0.55 × 0.55" (14 × 14 mm) copper pad areas.

Electrical Characteristics (T_A = 25 °C unless otherwise noted)

Items	Test conditions	Symbol	SK82~83	SK84	SK85~86	SK88~810	UNIT	
Instantaneous forward voltage	$I_F=8.0A^{(2)}$	V_F	0.50	0.55	0.70	0.85	V	
Reverse current	$V_R=V_{DC}$	I_R	1				20	mA
	$T_A=25^{\circ}C$ $T_A=100^{\circ}C$		10					

Note 2: Pulse test:300μs pulse width,1% duty cycle.



SK82~SK810

Surface Mount Schottky Rectifiers

Characteristic Curves ($T_A=25\text{ }^\circ\text{C}$ unless otherwise noted)

Fig.1 Forward Current Derating Curve

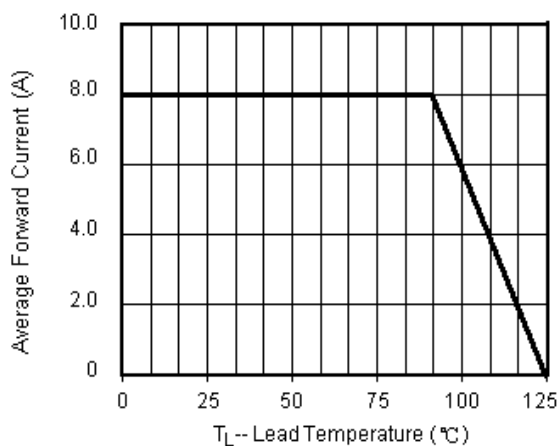


Fig.2 Maximum Non-Repetitive Peak Forward Surge Current

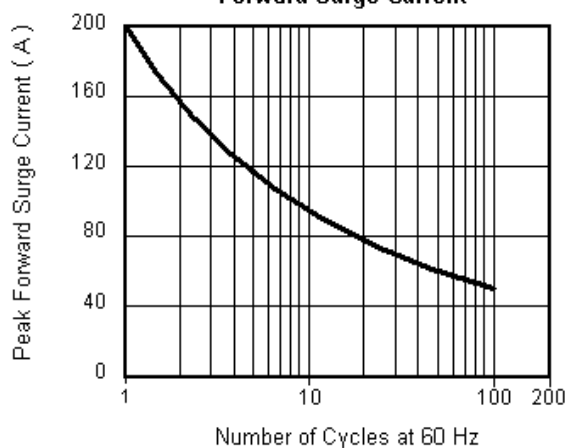


Fig.3 Typical Instantaneous Forward Characteristics

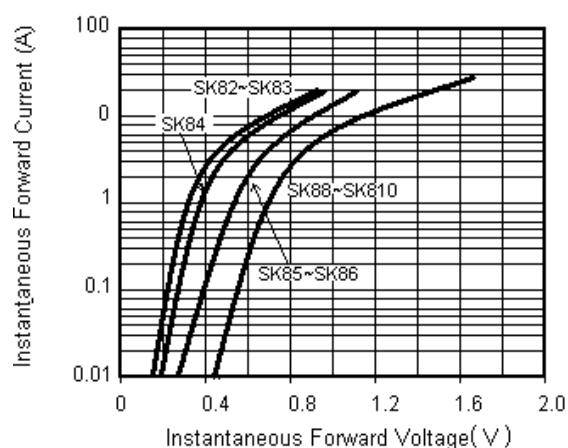
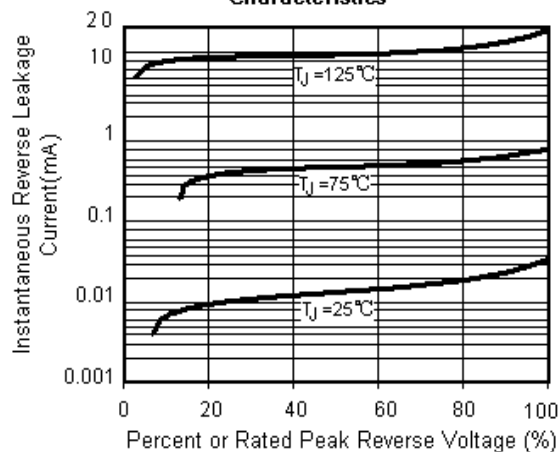
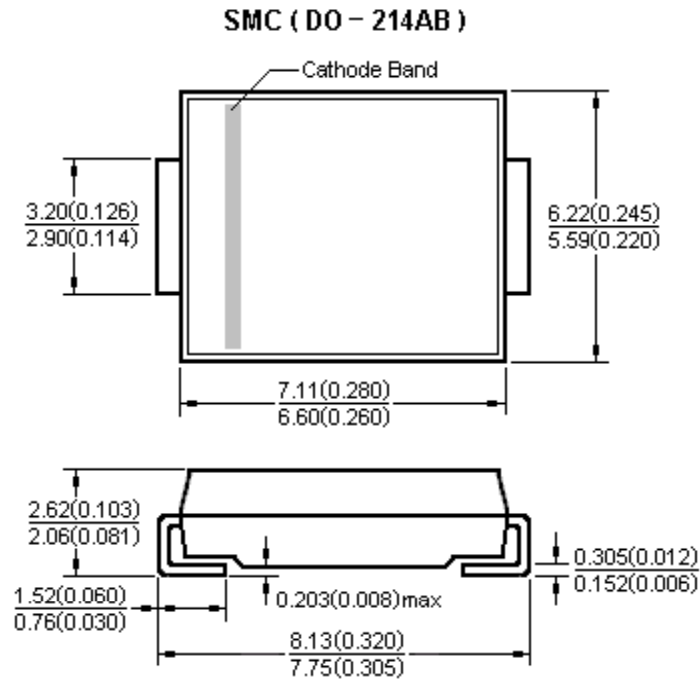


Fig.4 Typical Reverse Leakage Characteristics



**Package Outline****Notice**

- Product is intended for use in general electronics applications.
- Product should be worked less than the ratings; if exceeded, may cause permanent damage or introduce latent failure mechanisms.
- The absolute maximum ratings are rated values and must not be exceeded during operation. The following are the general derating methods you design a circuit with a device.
 - $I_{F(AV)}$: We recommend that the worst case current be no greater than 80% .
 - I_{FSM} : This rating specifies the non-repetitive peak current. This is only applied for an abnormal operation, which the general during the lifespan of the device.
 - T_J : Derate this rating when using a device in order to ensure high reliability. We recommend that the device be used at a T_J of below 125°C.

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